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LX5537

InGaP HBT 2.3 – 2.7 GHz Power Amplifier **PRODUCTION DATA SHEET**

DESCRIPTION

The LX5537 is a power amplifier optimized for 802.16e(WiMAX/WiBro) power detector at the output port of and 802.11b/g/n applications in the 2.3- the PA to help reduce BOM cost and 2.7 GHz frequency range. The PA is PCB space for implementation of implemented as a three-stage monolithic power control in a typical wireless microwave integrated circuit (MMIC) system. The 26dB with active bias, on-chip input matching function can optionally be used to and output pre-matching.

The device is manufactured with an InGaP/GaAs Heterojunction Bipolar pin 3mm x 3mm quad flat no lead Transistor (HBT) IC (MOCVD). It operates with a single compact footprint, low profile, and positive voltage supply of 3-4.2V, and excellent thermal capability make the provides power gain of 31dB and output LX5537 powers of +23.5dBm at 3.6V and +25 WiMAX/WiBro dBm at 4.2V for 2.5% EVM in the 2.5- 802.11b/g/n applications. 2.7GHz.

LX5537 also features an on-chip attenuation reach low gain mode.

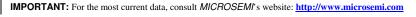
The LX5537 is available in a 16process package (OFN 3×3-16L). The an ideal solution for well as as

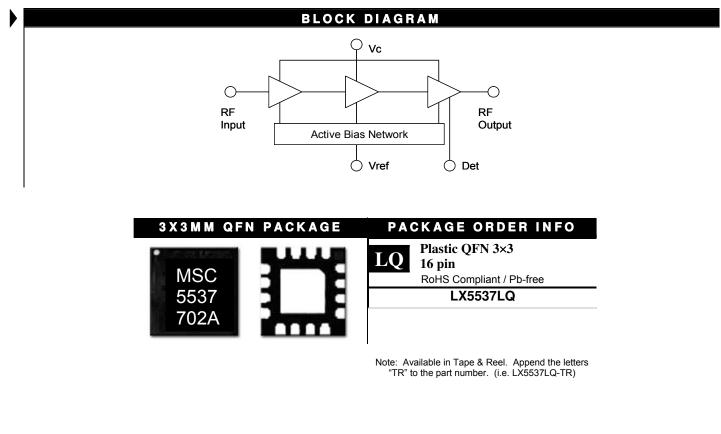
KEY FEATURES

- Advanced InGaP HBT
- 2.3-2.7GHz Operation
- . Single-Polarity 3-4.2V Supply
- Power Gain ~ 31 dB or higher
- 23.5 dBm @2.5% EVM /3.6V .
- 25 dBm @2.5% EVM /4.2V
- 24.5 dBm @4% EVM /3.6V .
- 26 dBm @4% EVM /4.2V 22% Efficiency @24.5dBm/3.6V
- Optional 26dB Attenuation
- Complete On-Chip Input Match
- Simple Output Match for
- **Optimal EVM**
- Temperature-Compensated **On-Chip Output Power Detector** with Wide Dynamic Range
- Small Footprint: 3x3mm²
- Low Profile: 0.9mm

APPLICATIONS

- 802.16e WiMAX
- 802.16e WiBro
- 802.11b/g/n





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INFORMATION

Thank you for your interest in Microsemi[®] Analog Mixed Signal products.

The full data sheet for this device contains proprietary information.

To obtain a copy, please contact your local Microsemi sales representative. The name of your local representative can be obtained at the following link http://www.microsemi.com/contact/contactfind.asp

or

Contact us directly by sending an email to:

IPGdatasheets@microsemi.com

Be sure to specify the data sheet you are requesting and include your company name and contact information and or vcard.

We look forward to hearing from you.